

LN62S

GaAs Infrared Light Emitting Diode

For optical control systems

This product can be combined with various types of silicon photodetectors such as the PN120S to form optical controllers.

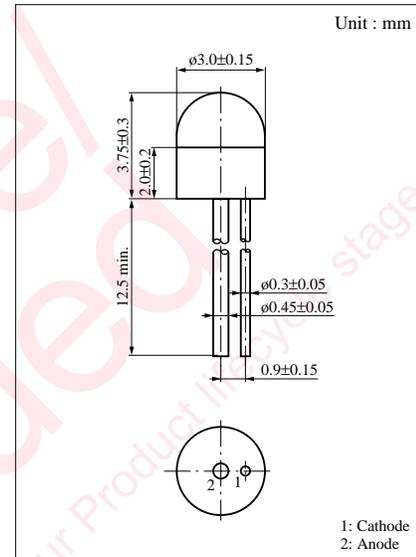
■ Features

- High-power output, high-efficiency : $P_O = 3.5 \text{ mW}$ (typ.)
- Infrared light emission close to monochromatic light : $\lambda_p = 950 \text{ nm}$ (typ.)
- Small ceramic package

■ Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

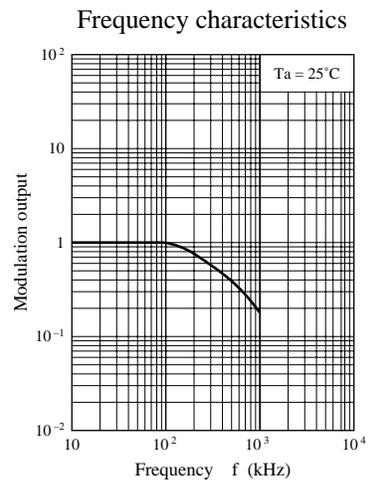
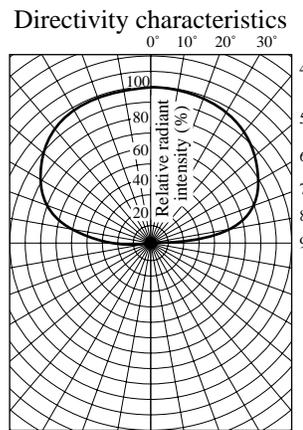
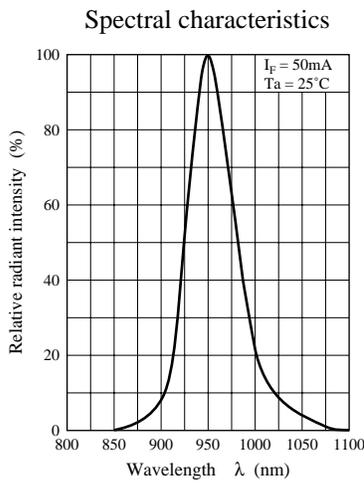
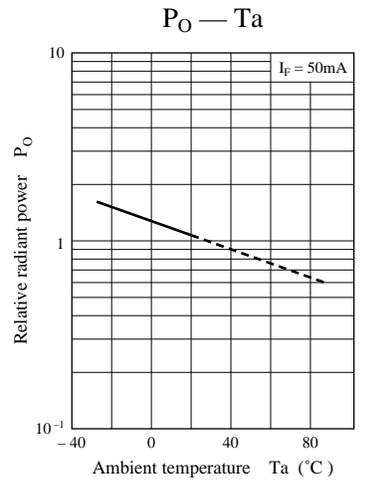
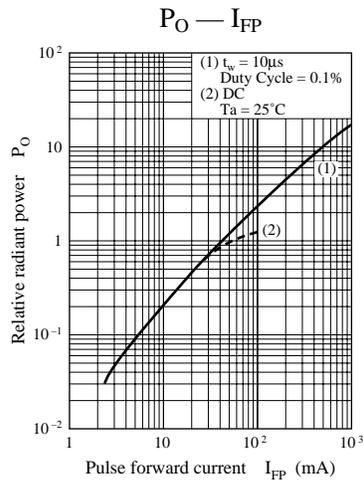
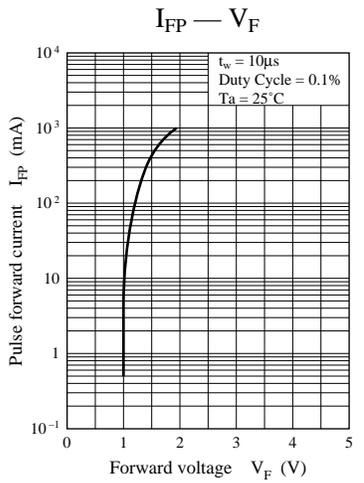
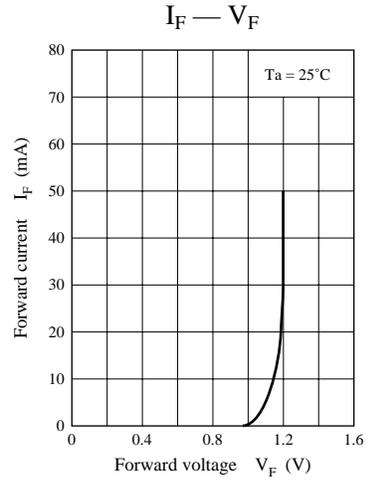
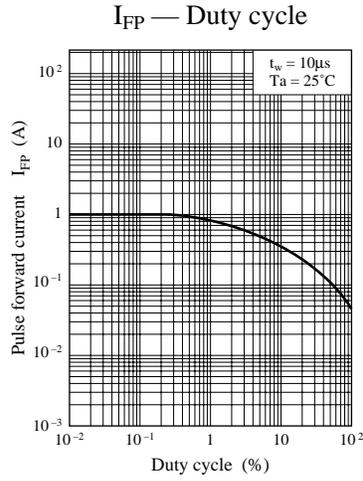
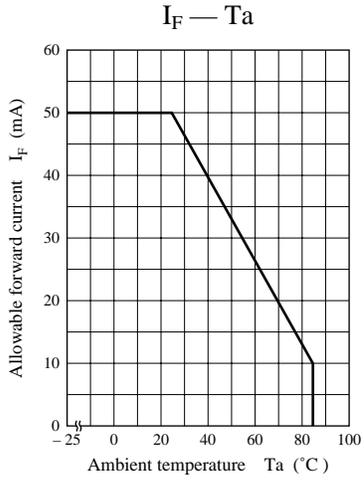
| Parameter | Symbol | Ratings | Unit |
|-------------------------------|------------|-------------|------------------|
| Power dissipation | P_D | 75 | mW |
| Forward current (DC) | I_F | 50 | mA |
| Pulse forward current | I_{FP}^* | 1 | A |
| Reverse voltage (DC) | V_R | 3 | V |
| Operating ambient temperature | T_{opr} | -25 to +85 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -30 to +100 | $^\circ\text{C}$ |

* $f = 100 \text{ Hz}$, Duty cycle = 0.1 %



■ Electro-Optical Characteristics ($T_a = 25^\circ\text{C}$)

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|--------------------------|-----------------|---------------------------------------------|-----|-----|-----|---------------|
| Radiant power | P_O | $I_F = 50 \text{ mA}$ | 1.5 | 3.5 | | mW |
| Peak emission wavelength | λ_p | $I_F = 50 \text{ mA}$ | | 950 | | nm |
| Spectral half band width | $\Delta\lambda$ | $I_F = 50 \text{ mA}$ | | 50 | | nm |
| Forward voltage (DC) | V_F | $I_F = 50 \text{ mA}$ | | 1.2 | 1.5 | V |
| Reverse current (DC) | I_R | $V_R = 3 \text{ V}$ | | | 10 | μA |
| Capacitance between pins | C_t | $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$ | | 50 | | pF |
| Half-power angle | θ | The angle in which radiant intensity is 50% | | 80 | | deg. |



Caution for Safety

 **DANGER**

■ This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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